NSN 5961-00-722-1266

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Inclosure Material:

Metal

Overall Length:

Between 0.215 inches and 0.320 inches

Overall Diameter:

Between 0.320 inches and 0.360 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown

voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

2.50 amperes source cutoff current

Power Rating Per Characteristic:

18.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0